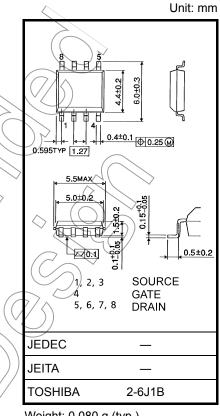
TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOS IV)

# **TPC8115**

Lithium Ion Battery Applications Notebook PC Applications Portable Equipment Applications

- Small footprint due to small and thin package
- Low drain-source ON resistance:  $RDS(ON) = 6.5 \text{ m}\Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 40 \text{ S (typ.)}$
- Low leakage current:  $IDSS = -10 \mu A \text{ (max) (VDS} = -20 \text{ V)}$
- Enhancement mode:  $V_{th} = -0.5$  to -1.2 V ( $V_{DS} = -10$  V,  $I_{D} = -1$  mA)

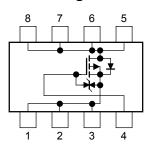


### Weight: 0.080 g (typ.)

# Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V <sub>DS</sub> S	-20	X
Drain-gate voltage (Ro	$_{\rm SS} = 20 \; \rm k\Omega)$	V <sub>DGR</sub>	_20	V
Gate-source voltage		VGSS	±8 <	\ v
Drain current	DC (Note 1)	De la companya de la	-10	A
	Pulse (Note 1)	/\DP	-40	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
Drain power dissipation	n (t = 10 s) (Note 2a)	PD	1:9	W
Drain power dissipation	n (t = 10/s) (Note 2b)	PD	1.0	W
Single pulse avalanche	e energy (Note 3)	EAS	26	mJ
Avalanche current	\ \ \ \	I <sub>AR</sub>	<del>-10</del>	Α
Repetitive avalanche energy (Note 2a) (Note 4)		EAR	0.19	mJ
Channel temperature		Tch	150	°C
Storage temperature ra	ange	T <sub>stg</sub>	-55 to 150	°C

## **Circuit Configuration**



Note: (Note 1), (Note 2), (Note 3) and (Note 4): See the next page.

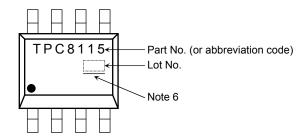
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Please handle with caution.

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R <sub>th (ch-a)</sub>	65.8	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R <sub>th (ch-a)</sub>	125	°C/W

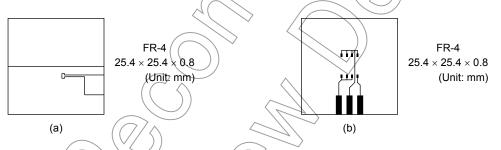
## Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C

#### Note 2:

(a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



Note 3:  $V_{DD} = -16 \text{ V}$ ,  $T_{ch} = 25^{\circ}\text{C}$  (initial), L = 0.2 mH,  $R_G = 25 \Omega$ ,  $I_{AR} = -10 \text{ A}$ 

Note 4: Repetitive rating; pulse width limited by maximum channel temperature

Note 5: • on lower left of the marking indicates Pin 1.

Weekly code: (Three digits)
 Week of manufacture
 (01 for the first week of a year: sequential number up to 52 or 53)
 Year of manufacture
 (The last digit of a year)

Note 6: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

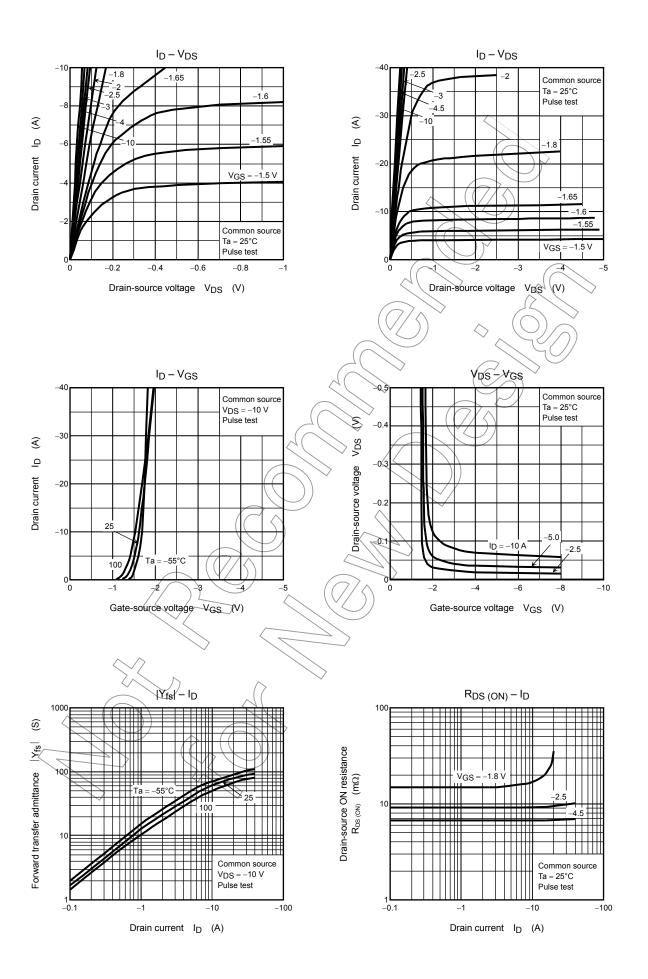
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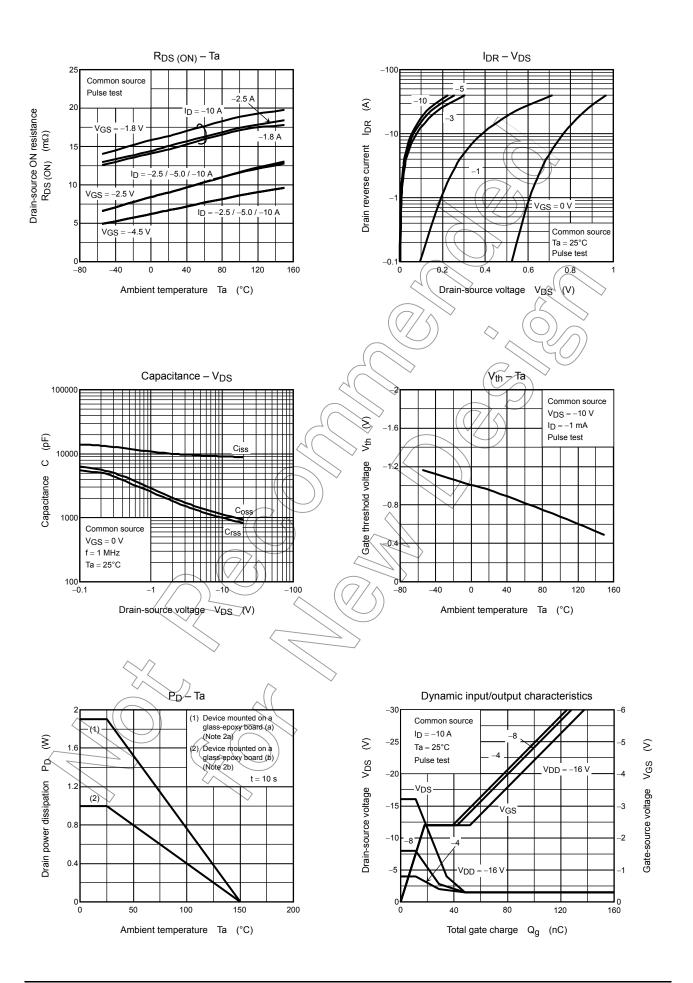
# **Electrical Characteristics (Ta = 25°C)**

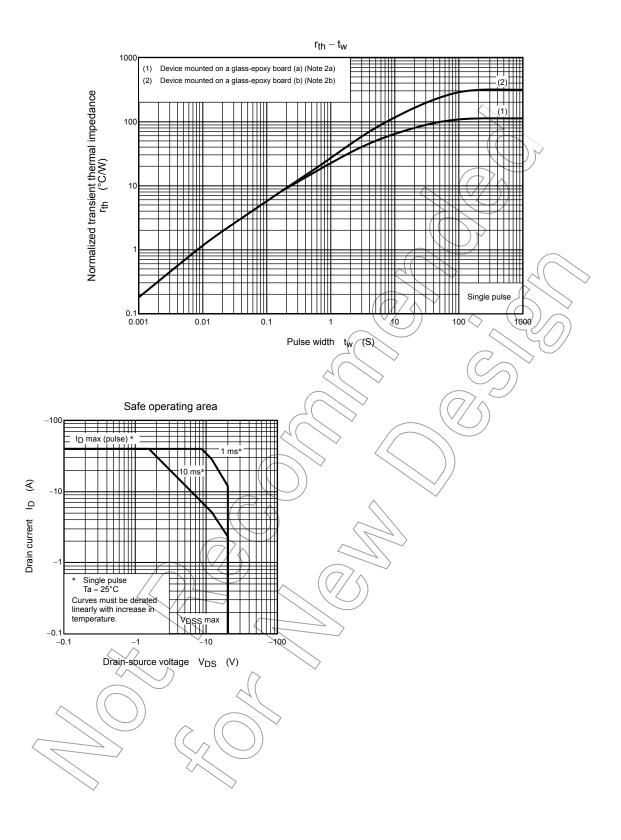
Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curre	ent	I <sub>GSS</sub>	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Drain cut-OFF curr	ent	I <sub>DSS</sub>	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$	_	_	-10	μА
Drain-source breakdown voltage		V <sub>(BR) DSS</sub>	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-20	_		V
		V <sub>(BR) DSX</sub>	$I_D = -10 \text{ mA}, V_{GS} = 8 \text{ V}$	10	_	_	, v
Gate threshold volt	age	V <sub>th</sub>	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$	\ <del>-</del> 0.5	) /	-1.2	V
			$V_{GS} = -1.8 \text{ V}, I_D = -5.0 \text{ A}$	$\nearrow$	15	30	
Drain-source ON resistance		R <sub>DS</sub> (ON)	$V_{GS} = -2.5 \text{ V}, I_D = -5.0 \text{ A}$	$\rightarrow$	9.0	14	mΩ
			$V_{GS} = -4.5 \text{ V}, I_D = -5.0 \text{ A}$	_	6.5	10	
Forward transfer ad	dmittance	Y <sub>fs</sub>	$V_{DS} = -10 \text{ V}, I_D = -5.0 \text{ A}$	20	40	_	S
Input capacitance		C <sub>iss</sub>		_	9130	_	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		1020	$\searrow$	pF
Output capacitance	•	C <sub>oss</sub>		-	1110	> —	
Switching time	Rise time	t <sub>r</sub>	V <sub>GS</sub> 0V 1 <sub>D</sub> = -5 A		14	) —	
	Turn-ON time	t <sub>on</sub>	VGS 5V COUT		26	_	ns
	Fall time	t <sub>f</sub>	7.4 m m 0 %		228		110
	Turn-OFF time	t <sub>off</sub>	Duty $\leq$ 1%, $t_W = 10 \mu s$		666		
Total gate charge (gate-source plus gate-drain)		Qg	V <sub>DD</sub> ≈ -16 V, V <sub>GS</sub> = -5 V,	_	115		
Gate-source charge 1		Q <sub>gs1</sub>	$I_D = -10 \text{ A}$	_	18	_	nC
Gate-drain ("miller") charge		Qgd		_	34	_	

# Source-Drain Ratings and Characteristics (Ta = 25°C)

Charac	eteristics	Symbol Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse (Note 1)	JDRR -			-40	Α
Forward voltage (died	de)	$V_{DSF}$ $I_{DR} = -10 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	1.2	V







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